

SD103AWS

40V-0.35A Schottky Barrier Diode

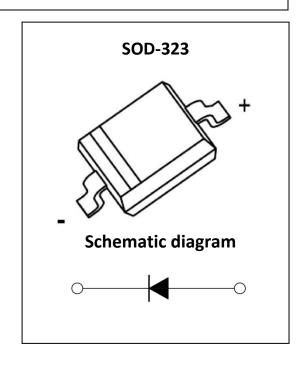
SD103AWS Schottky Barrier Diode

Feature

- Low Forward Voltage Drop
- Low VF
- Low IR
- High Reliability

MARKING:





ABSOLUTE MAXIMUM RATINGS (T_A=25℃ unless otherwise noted)

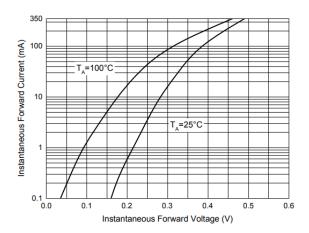
Parameter	Symbol	Value	Unit
DC Reverse Voltage	V _R	40	V
RMS Reverse Voltage	$V_{R(RMS)}$	28	V
Forward Continuous Current	I _{FM}	0.35	А
Non-repetitive Peak Forward Surge Current @ t=8.3ms	I _{FSM}	2	А
Power Dissipation	P _D	0.2	W
Junction Temperature	TJ	125	$^{\circ}$ C
Storage Temperature	T _{STG}	-55 ~ +125	$^{\circ}$ C

ELECTRICAL CHARACTERISTICS (T_A =25 $^{\circ}$ C unless otherwise noted)

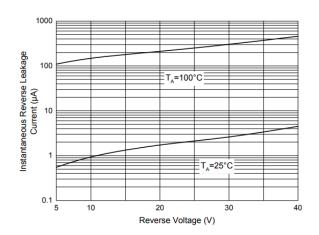
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Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Reverse Voltage	V_{BR}	I _R =100μA	40			V
Forward Voltage	VF	I _F =20mA			0.37	V
		I _F =200mA			0.60	V
Reverse Current	I _R	V _R =30V			5	μΑ
Capacitance Between		V -0 f-4MI-			50	F
Terminals	Ст	V _R =0, f=1MHz			30	pF
Reverse Recovery Time	trr	I _F =I _R =200Ma,Irr=0.1*I _R ,R _L =100 Ω		10		ns



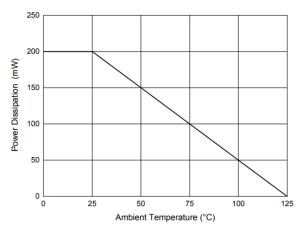
Typical Characteristics



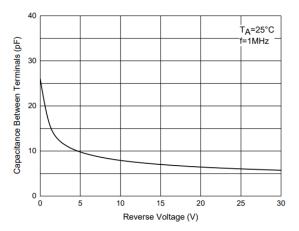
Typical Instantaneous Forward Characteristics



Typical Reverse Leakage Characteristics



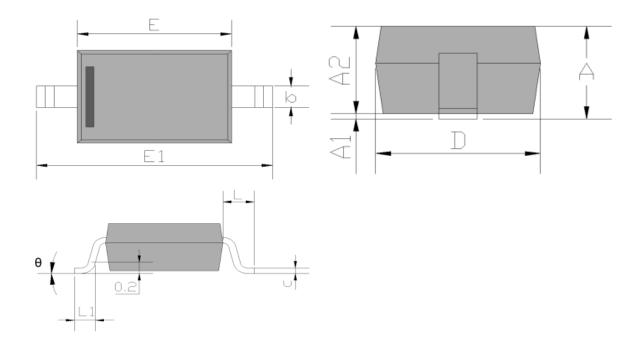
Power Derating Curve



Capacitance Characteristics



SOD-323 Package Outline Dimensions



	Dimensions in mm			
Symbol	Min.	Max.		
Α		1.000		
A1	0.000	0.100		
A2	0.800	0.900		
b	0.250	0.350		
С	0.080	0.150		
D	1.200	1.400		
E	1.600	1.800		
E1	2.500	2.700		
L	0.475 REF.			
L1	0.250	0.400		
θ	0°	8°		





Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or
 property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
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